

60 V, N-channel Trench MOSFET

11 January 2024

1. General description

N-channel enhancement mode Field-Effect Transistor (FET) in a small SOT23 Surface-Mounted Device (SMD) plastic package using Trench MOSFET technology.

2. Features and benefits

- Logic-level compatible
- Extended temperature range T_i = 175 °C
- Trench MOSFET technology
- ElectroStatic Discharge (ESD) protection
- AEC-Q101 qualified

3. Applications

- Relay driver
- High-speed line driver
- Low-side load switch
- Switching circuits

4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Мах	Unit
V _{DS}	drain-source voltage	T _j = 25 °C		-	-	60	V
V _{GS}	gate-source voltage	_		-20	-	20	V
I _D	drain current	V _{GS} = 10 V; T _{amb} = 25 °C	[1]	-	-	250	mA
Static chara	octeristics						
R _{DSon}	drain-source on-state resistance	V _{GS} = 10 V; I _D = 100 mA; T _j = 25 °C		-	2.2	3	Ω

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for drain 1 cm².



5. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	G	gate		D
2	S	source		
3	D	drain		G G S 017aaa255

6. Ordering information

Table 3. Ordering information						
Type number	Package					
	Name	Description	Version			
BSS138AK-Q		plastic, surface-mounted package; 3 terminals; 1.9 mm pitch; 2.9 mm x 1.3 mm x 1 mm body	SOT23			

7. Marking

Table 4. Marking codes

Type number	Marking code[1]
BSS138AK-Q	J5%

[1] % = placeholder for manufacturing site code

BSS138AK-Q

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8. Limiting values

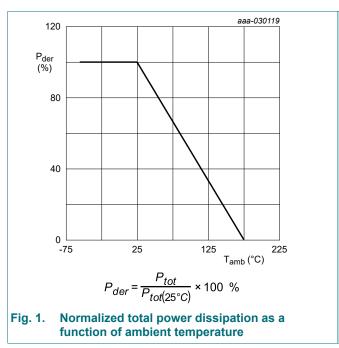
Table 5. Limiting values

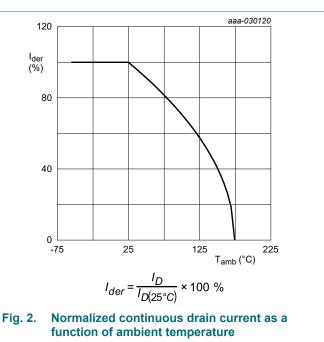
In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Мах	Unit
V _{DS}	drain-source voltage	T _j = 25 °C		-	60	V
V _{GS}	gate-source voltage			-20	20	V
I _D	drain current	V _{GS} = 10 V; T _{amb} = 25 °C	[1]	-	250	mA
		V _{GS} = 10 V; T _{amb} = 100 °C	[1]	-	180	mA
I _{DM}	peak drain current	T_{amb} = 25 °C; single pulse; $t_p \le 10 \ \mu s$		-	2	A
P _{tot}	total power dissipation	T _{amb} = 25 °C	[2]	-	320	mW
			[1]	-	390	mW
		T _{sp} = 25 °C		-	1.6	W
Tj	junction temperature			-55	175	°C
T _{amb}	ambient temperature			-55	175	°C
T _{stg}	storage temperature			-65	175	°C
Source-drai	n diode					
Is	source current	T _{amb} = 25 °C	[1]	-	250	mA
ESD maxim	um rating					
V _{ESD}	electrostatic discharge voltage	НВМ		-	500	V
Avalanche r	uggedness					
E _{DS(AL)S}	non-repetitive drain- source avalanche energy	$T_{j(init)} = 25 \text{ °C; } I_D = 20 \text{ mA; DUT in}$ avalanche (unclamped)		-	6.6	mJ

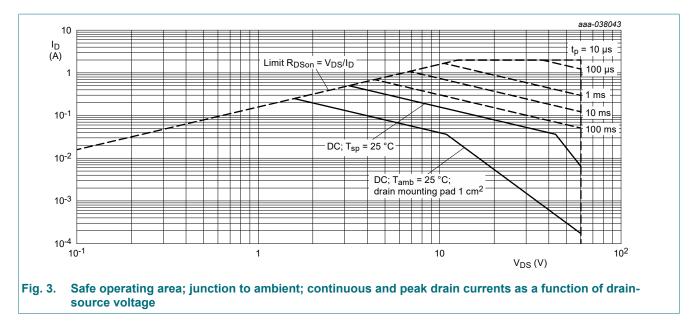
[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for drain 1 cm².

[2] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.





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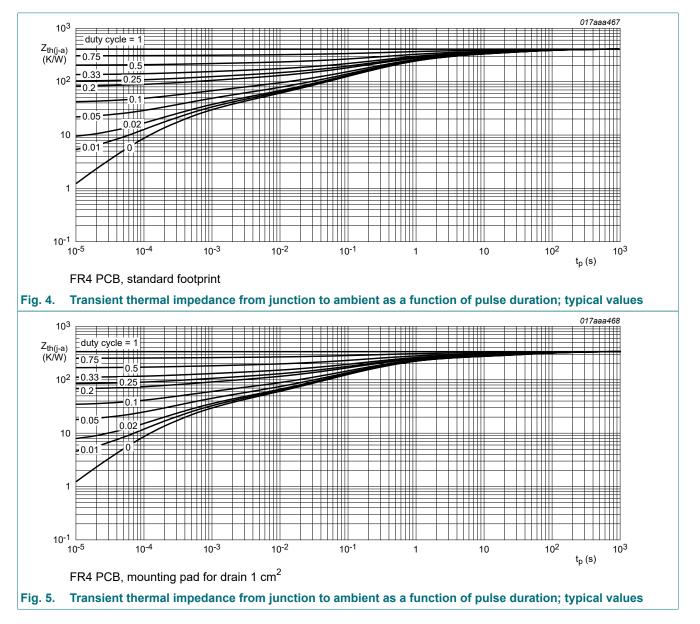


9. Thermal characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
R _{th(j-a)} thermal resistance from junction to ambient	thermal resistance from	in free air	[1]	-	410	470	K/W
	[2	[2]	-	330	380	K/W	
R _{th(j-sp)}	thermal resistance from junction to solder point			-	80	95	K/W

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

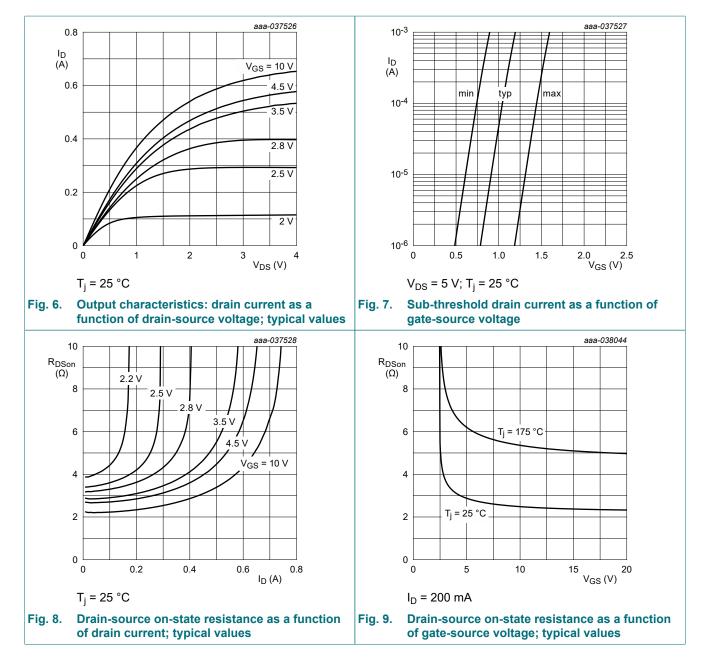
[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for drain 1 cm².



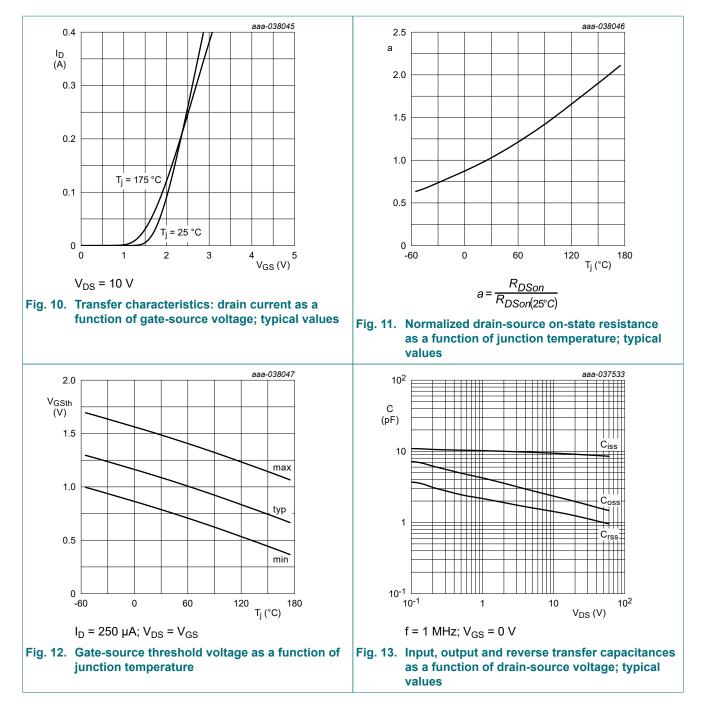
10. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static chara	acteristics					
V _{(BR)DSS}	drain-source breakdown voltage	I _D = 250 μA; V _{GS} = 0 V; T _j = 25 °C	60	-	-	V
V _{GSth}	gate-source threshold voltage	I _D = 250 μA; V _{DS} = V _{GS} ; T _j = 25 °C	0.8	1.1	1.5	V
I _{DSS}	drain leakage current	V _{DS} = 60 V; V _{GS} = 0 V; T _j = 25 °C	-	-	500	nA
		V _{DS} = 60 V; V _{GS} = 0 V; T _j = 125 °C	-	-	5	μA
I _{GSS}	gate leakage current	V _{GS} = 20 V; V _{DS} = 0 V; T _j = 25 °C	-	-	10	μA
		V _{GS} = -20 V; V _{DS} = 0 V; T _j = 25 °C	-	-	-10	μA
		V _{GS} = 10 V; V _{DS} = 0 V; T _j = 25 °C	-	-	1	μA
		V _{GS} = -10 V; V _{DS} = 0 V; T _j = 25 °C	-	-	-1	μA
		V _{GS} = 4.5 V; V _{DS} = 0 V; T _j = 25 °C	-	-	500	nA
		V _{GS} = -4.5 V; V _{DS} = 0 V; T _j = 25 °C	-	-	-500	nA
R _{DSon}	drain-source on-state resistance	V _{GS} = 10 V; I _D = 100 mA; T _j = 25 °C	-	2.2	3	Ω
		V _{GS} = 10 V; I _D = 100 mA; T _j = 175 °C	-	4.6	6.3	Ω
		V _{GS} = 4.5 V; I _D = 50 mA; T _j = 25 °C	-	2.7	3.9	Ω
		V _{GS} = 2.5 V; I _D = 10 mA; T _j = 25 °C	-	3.4	12	Ω
9 _{fs}	forward transconductance	V _{DS} = 5 V; I _D = 100 mA; T _j = 25 °C	-	0.3	-	S
Dynamic ch	naracteristics					
Q _{G(tot)}	total gate charge	V_{DS} = 30 V; I _D = 100 mA; V _{GS} = 10 V;	-	0.21	0.315	nC
Q _{GS}	gate-source charge	T _j = 25 °C	-	0.022	-	nC
Q _{GD}	gate-drain charge	1 1	-	0.051	-	nC
C _{iss}	input capacitance	V _{DS} = 30 V; f = 1 MHz; V _{GS} = 0 V;	-	9	-	pF
C _{oss}	output capacitance	T _j = 25 °C	-	1.8	-	pF
C _{rss}	reverse transfer capacitance		-	1.1	-	pF
t _{d(on)}	turn-on delay time	V_{DS} = 30 V; I _D = 100 mA; V _{GS} = 10 V;	-	1	-	ns
t _r	rise time	$R_{G(ext)} = 6 \Omega; T_j = 25 °C$	-	1	-	ns
t _{d(off)}	turn-off delay time	1 1	-	2	-	ns
t _f	fall time	1 1	-	3	-	ns
Source-drai	in diode	·				
V _{SD}	source-drain voltage	I_{S} = 250 mA; V_{GS} = 0 V; T_{j} = 25 °C	-	1	1.7	V
t _{rr}	reverse recovery time	I _S = 250 mA; dI _S /dt = -100 A/μs;	-	7	-	ns
Qr	recovered charge	V _{GS} = 0 V; V _{DS} = 30 V; T _j = 25 °C	-	1	-	nC

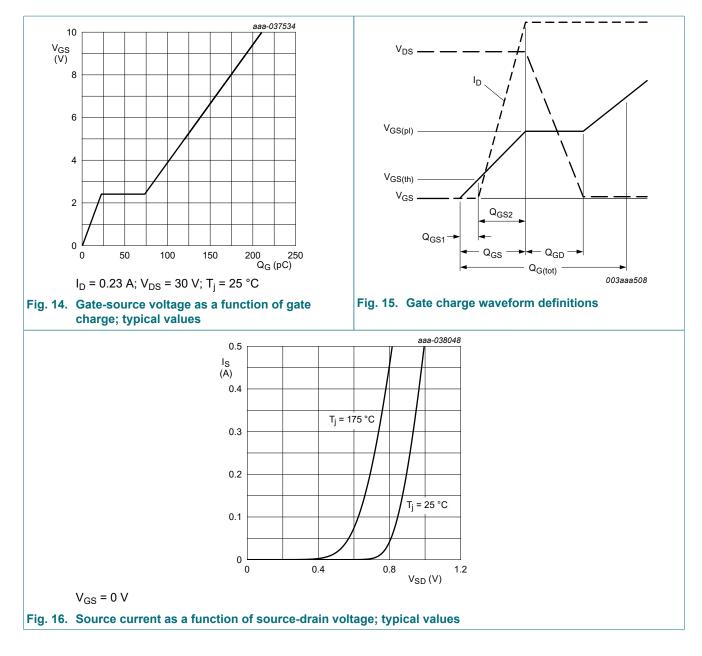
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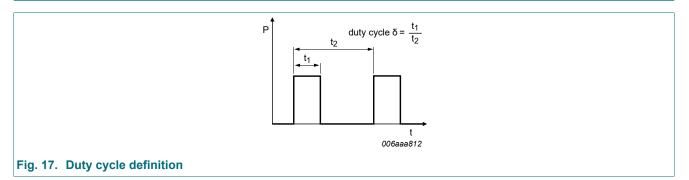
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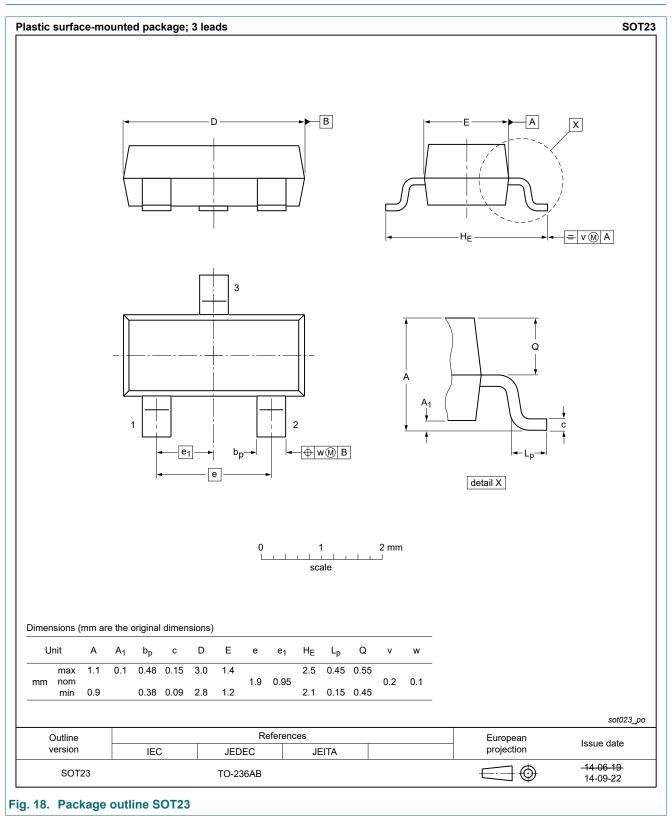
11. Test information



Quality information

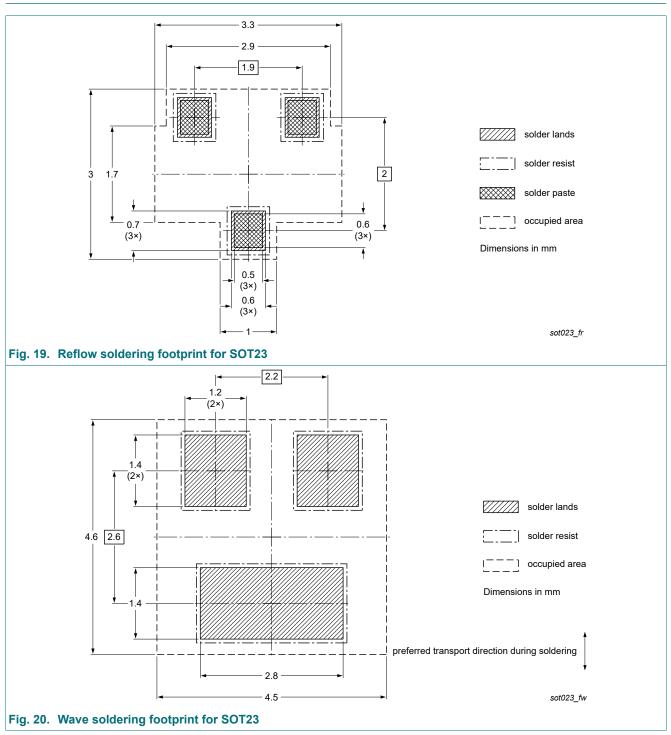
This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard *Q101* - *Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

12. Package outline



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13. Soldering



Product data sheet

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14. Revision history

Table 8. Revision history						
Data sheet ID	Release date	Data sheet status	Change notice	Supersedes		
BSS138AK-Q v.1	20240111	Product data sheet	-	-		

15. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

 Please consult the most recently issued document before initiating or completing a design.

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